PENDING CLAIMS

What follows is a complete list of claims currently pending in the application.

Please amend claims 1 and 2 as shown below.

- (Previously amended) A three dimensional multi-level memory array disposed above a substrate, the array comprising:
 - a first plurality of spaced-apart rail-stacks disposed at a first height in a first direction above the substrate;
 - a second plurality of spaced-apart rail-stacks disposed above the first height and in a second direction different from the first direction; and
 - a plurality of memory cells, each memory cell comprising a silicon nitride antifuse,
 - wherein the antifuses are disposed at the intersections of the first railstacks and the second rail-stacks.
- (Currently amended) The array of claim 1, further comprising polysilicon p+ndiodes or polysilicon p-n+ diodes.